

MMBZ5V6ALT1 Series

Preferred Device

24 and 40 Watt Peak Power Zener Transient Voltage Suppressors

SOT-23 Dual Common Anode Zeners for ESD Protection

These dual monolithic silicon Zener diodes are designed for applications requiring transient overvoltage protection capability. They are intended for use in voltage and ESD sensitive equipment such as computers, printers, business machines, communication systems, medical equipment and other applications. Their dual junction common anode design protects two separate lines using only one package. These devices are ideal for situations where board space is at a premium.

Features

- Pb-Free Packages are Available
- SOT-23 Package Allows Either Two Separate Unidirectional Configurations or a Single Bidirectional Configuration
- Working Peak Reverse Voltage Range – 3 V to 26 V
- Standard Zener Breakdown Voltage Range – 5.6 V to 33 V
- Peak Power – 24 or 40 Watts @ 1.0 ms (Unidirectional), per Figure 5 Waveform
- ESD Rating of Class N (exceeding 16 kV) per the Human Body Model
- Maximum Clamping Voltage @ Peak Pulse Current
- Low Leakage < 5.0 μ A
- Flammability Rating UL 94 V-O

Mechanical Characteristics

CASE: Void-free, transfer-molded, thermosetting plastic case

FINISH: Corrosion resistant finish, easily solderable

MAXIMUM CASE TEMPERATURE FOR SOLDERING PURPOSES:

260°C for 10 Seconds

Package designed for optimal automated board assembly

Small package size for high density applications

Available in 8 mm Tape and Reel

Use the Device Number to order the 7 inch/3,000 unit reel.

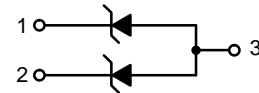
Replace the “T1” with “T3” in the Device Number to order the

13 inch/10,000 unit reel.

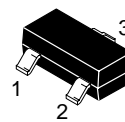


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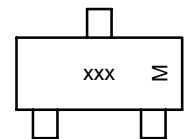
<http://onsemi.com>



MARKING DIAGRAM



SOT-23
CASE 318
STYLE 12



xxx = Device Code

M = Date Code

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 2 of this data sheet.

DEVICE MARKING INFORMATION

See specific marking information in the device marking column of the table on page 3 of this data sheet.

Preferred devices are recommended choices for future use and best overall value.

MMBZ5V6ALT1 Series

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Peak Power Dissipation @ 1.0 ms (Note 1) MMBZ5V6ALT1 thru MMBZ10VALT1 @ $T_L \leq 25^\circ\text{C}$ MMBZ12VALT1 thru MMBZ33VALT1	P_{pk}	24 40	Watts
Total Power Dissipation on FR-5 Board (Note 2) @ $T_A = 25^\circ\text{C}$ Derate above 25°C	P_D	225 1.8	mW mW/ $^\circ\text{C}$
Thermal Resistance Junction-to-Ambient	$R_{\theta JA}$	556	$^\circ\text{C}/\text{W}$
Total Power Dissipation on Alumina Substrate (Note 3) @ $T_A = 25^\circ\text{C}$ Derate above 25°C	P_D	300 2.4	mW mW/ $^\circ\text{C}$
Thermal Resistance Junction-to-Ambient	$R_{\theta JA}$	417	$^\circ\text{C}/\text{W}$
Junction and Storage Temperature Range	T_J, T_{stg}	- 55 to +150	$^\circ\text{C}$
Lead Solder Temperature – Maximum (10 Second Duration)	T_L	260	$^\circ\text{C}$

Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.

1. Non-repetitive current pulse per Figure 5 and derate above $T_A = 25^\circ\text{C}$ per Figure 6.

2. FR-5 = 1.0 x 0.75 x 0.62 in.

3. Alumina = 0.4 x 0.3 x 0.024 in, 99.5% alumina.

*Other voltages may be available upon request.

ORDERING INFORMATION

Device	Package	Shipping†
MMBZ5V6ALT1	SOT-23	3000 Tape & Reel
MMBZ5V6ALT1G	SOT-23 (Pb-Free)	3000 Tape & Reel
MMBZ5V6ALT3	SOT-23	10,000 Tape & Reel
MMBZ5V6ALT3G	SOT-23 (Pb-Free)	10,000 Tape & Reel
MMBZ6VxALT1	SOT-23	3000 Tape & Reel
MMBZ6VxALT1G	SOT-23 (Pb-Free)	3000 Tape & Reel
MMBZ6VxALT3	SOT-23	10,000 Tape & Reel
MMBZ6VxALT3G	SOT-23 (Pb-Free)	10,000 Tape & Reel
MMBZ9V1ALT1	SOT-23	3000 Tape & Reel
MMBZ9V1ALT1G	SOT-23 (Pb-Free)	3000 Tape & Reel
MMBZ9V1ALT3	SOT-23	10,000 Tape & Reel
MMBZ9V1ALT13G	SOT-23 (Pb-Free)	10,000 Tape & Reel
MMBZxxVALT1	SOT-23	3000 Tape & Reel
MMBZxxVALT1G	SOT-23 (Pb-Free)	3000 Tape & Reel
MMBZxxVALT3	SOT-23	10,000 Tape & Reel
MMBZxxVALT3G	SOT-23 (Pb-Free)	10,000 Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

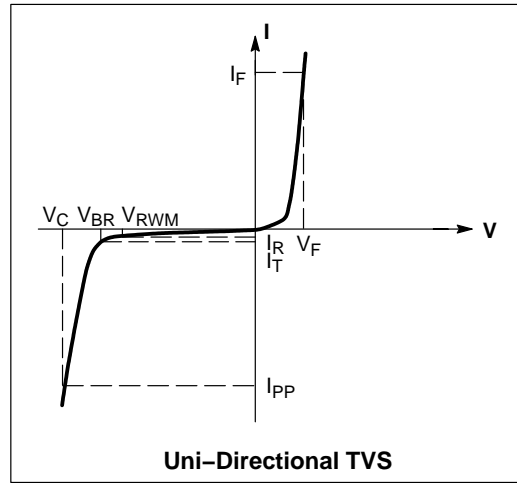
MMBZ5V6ALT1 Series

ELECTRICAL CHARACTERISTICS

($T_A = 25^\circ\text{C}$ unless otherwise noted)

UNIDIRECTIONAL (Circuit tied to Pins 1 and 3 or 2 and 3)

Symbol	Parameter
I_{PP}	Maximum Reverse Peak Pulse Current
V_C	Clamping Voltage @ I_{PP}
V_{RWM}	Working Peak Reverse Voltage
I_R	Maximum Reverse Leakage Current @ V_{RWM}
V_{BR}	Breakdown Voltage @ I_T
I_T	Test Current
ΘV_{BR}	Maximum Temperature Coefficient of V_{BR}
I_F	Forward Current
V_F	Forward Voltage @ I_F
Z_{ZT}	Maximum Zener Impedance @ I_{ZT}
I_{ZK}	Reverse Current
Z_{ZK}	Maximum Zener Impedance @ I_{ZK}



ELECTRICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$ unless otherwise noted)

UNIDIRECTIONAL (Circuit tied to Pins 1 and 3 or Pins 2 and 3)

($V_F = 0.9\text{ V Max @ } I_F = 10\text{ mA}$)

24 WATTS

Device	Device Marking	V_{RWM} Volts	$I_R @ V_{RWM}$ μA	Breakdown Voltage				Max Zener Impedance (Note 5)			$V_C @ I_{PP}$ (Note 6)		ΘV_{BR} $\text{mV}/^\circ\text{C}$
				V_{BR} (Note 4) (V)			@ I_T mA	$Z_{ZT} @ I_{ZT}$ Ω	$Z_{ZK} @ I_{ZK}$ Ω	V_C V	I_{PP} A		
				Min	Nom	Max							
MMBZ5V6AL	5A6	3.0	5.0	5.32	5.6	5.88	20	11	1600	0.25	8.0	3.0	1.26
MMBZ6V2AL	6A2	3.0	0.5	5.89	6.2	6.51	1.0	-	-	-	8.7	2.76	2.80
MMBZ6V8AL	6A8	4.5	0.5	6.46	6.8	7.14	1.0	-	-	-	9.6	2.5	3.4
MMBZ9V1AL	9A1	6.0	0.3	8.65	9.1	9.56	1.0	-	-	-	14	1.7	7.5
MMBZ10VAL	10A	6.5	0.3	9.50	10	10.5	1.0	-	-	-	14.2	1.7	7.5

($V_F = 0.9\text{ V Max @ } I_F = 10\text{ mA}$)

40 WATTS

Device	Device Marking	V_{RWM} Volts	$I_R @ V_{RWM}$ nA	Breakdown Voltage				$V_C @ I_{PP}$ (Note 6)		ΘV_{BR} $\text{mV}/^\circ\text{C}$
				V_{BR} (Note 4) (V)			@ I_T mA	V_C V	I_{PP} A	
				Min	Nom	Max				
MMBZ12VAL	12A	8.5	200	11.40	12	12.60	1.0	17	2.35	7.5
MMBZ15VAL	15A	12	50	14.25	15	15.75	1.0	21	1.9	12.3
MMBZ18VAL	18A	14.5	50	17.10	18	18.90	1.0	25	1.6	15.3
MMBZ20VAL	20A	17	50	19.00	20	21.00	1.0	28	1.4	17.2
MMBZ27VAL	27A	22	50	25.65	27	28.35	1.0	40	1.0	24.3
MMBZ33VAL	33A	26	50	31.35	33	34.65	1.0	46	0.87	30.4

4. V_{BR} measured at pulse test current I_T at an ambient temperature of 25°C .

5. Z_{ZT} and Z_{ZK} are measured by dividing the AC voltage drop across the device by the AC current applied. The specified limits are for $I_{Z(AC)} = 0.1 I_{Z(DC)}$, with the AC frequency = 1.0 kHz.

6. Surge current waveform per Figure 5 and derate per Figure 6

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TYPICAL CHARACTERISTICS

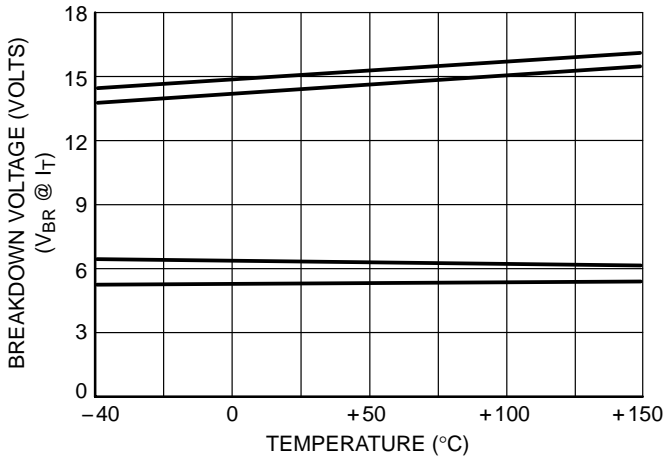


Figure 1. Typical Breakdown Voltage versus Temperature

(Upper curve for each voltage is bidirectional mode, lower curve is unidirectional mode)

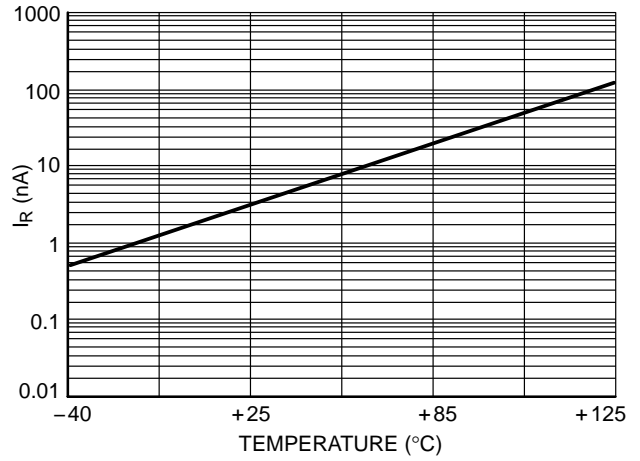


Figure 2. Typical Leakage Current versus Temperature

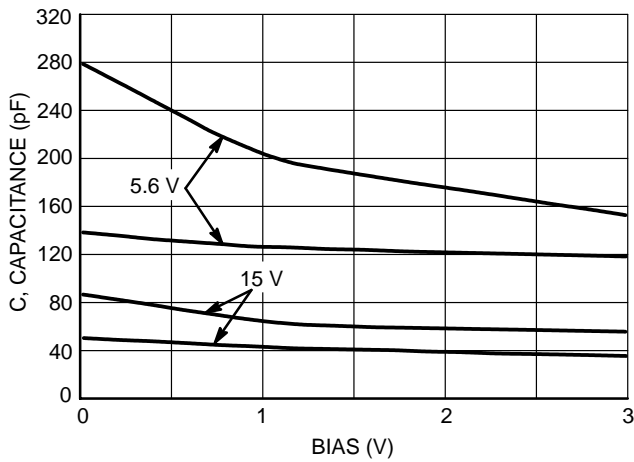


Figure 3. Typical Capacitance versus Bias Voltage

(Upper curve for each voltage is unidirectional mode, lower curve is bidirectional mode)

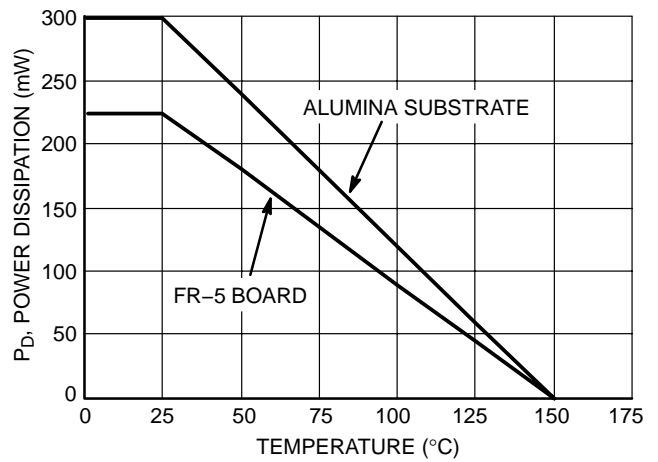


Figure 4. Steady State Power Derating Curve

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TYPICAL CHARACTERISTICS

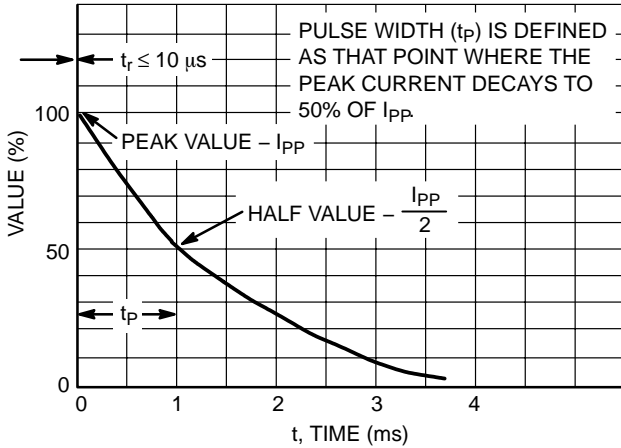


Figure 5. Pulse Waveform

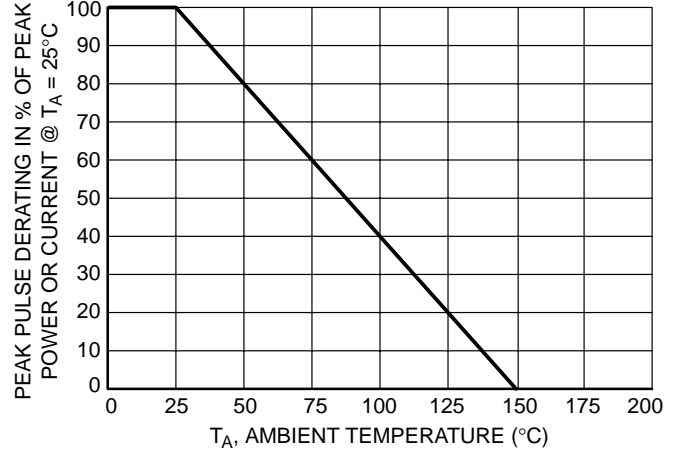


Figure 6. Pulse Derating Curve

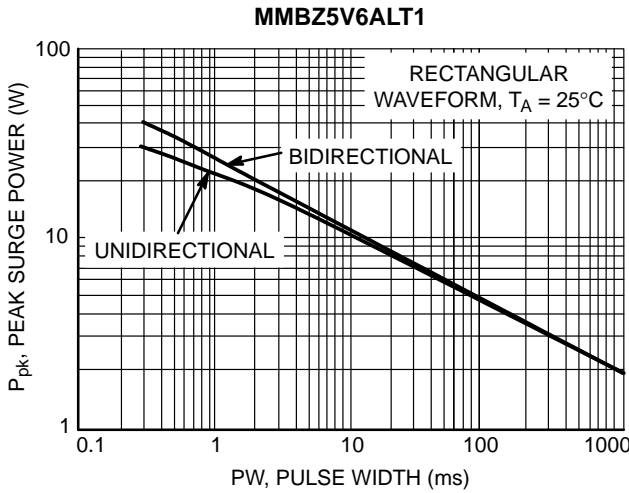


Figure 7. Maximum Non-repetitive Surge Power, P_{pk} versus PW

Power is defined as $V_{RSM} \times I_Z(pk)$ where V_{RSM} is the clamping voltage at $I_Z(pk)$.

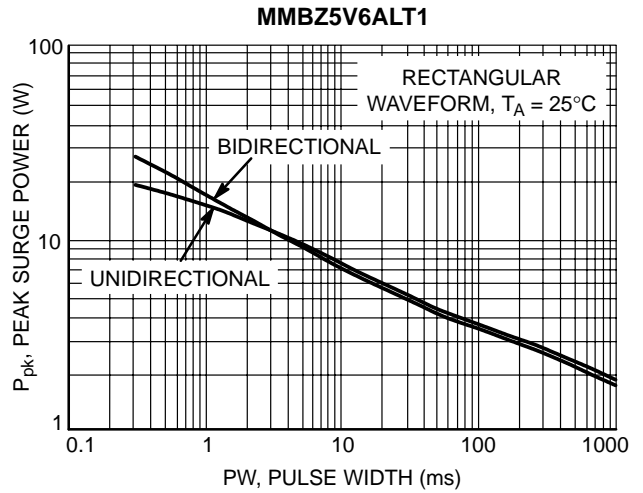


Figure 8. Maximum Non-repetitive Surge Power, $P_{pk(NOM)}$ versus PW

Power is defined as $V_Z(NOM) \times I_Z(pk)$ where $V_Z(NOM)$ is the nominal Zener voltage measured at the low test current used for voltage classification.

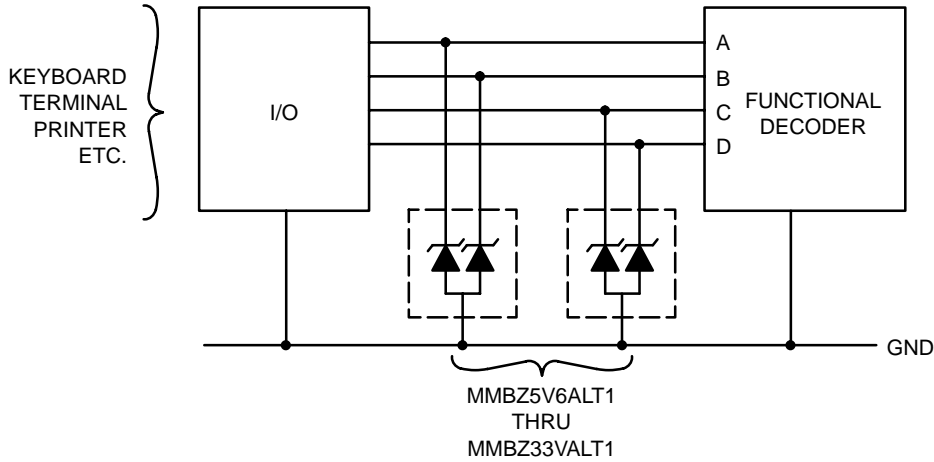
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TYPICAL COMMON ANODE APPLICATIONS

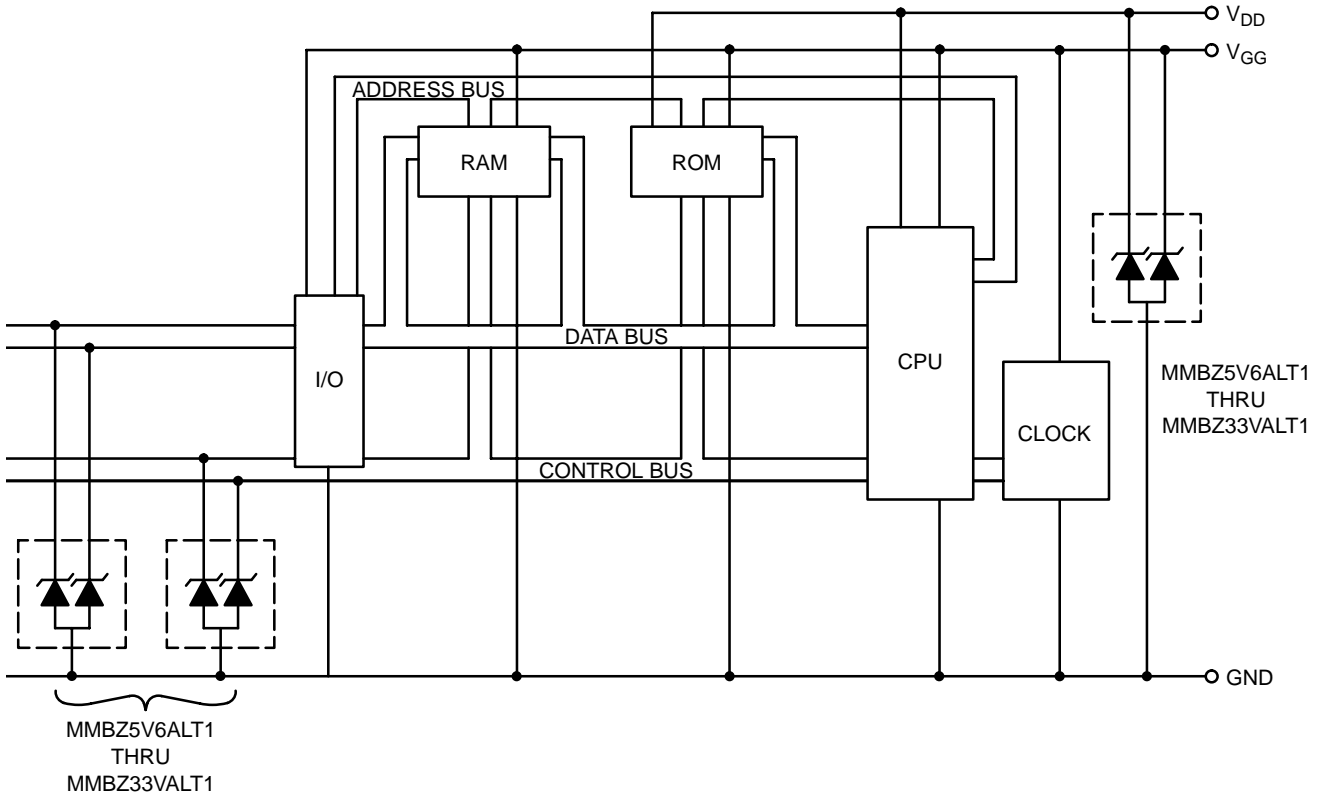
A quad junction common anode design in a SOT-23 package protects four separate lines using only one package. This adds flexibility and creativity to PCB design especially

when board space is at a premium. Two simplified examples of TVS applications are illustrated below.

Computer Interface Protection



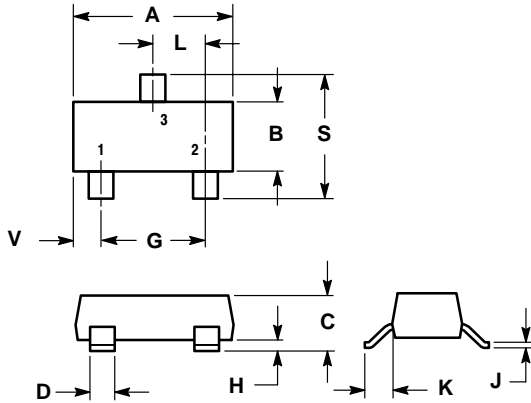
Microprocessor Protection



MMBZ5V6ALT1 Series

PACKAGE DIMENSIONS

SOT-23 (TO-236)
CASE 318-09
ISSUE AH



NOTES:

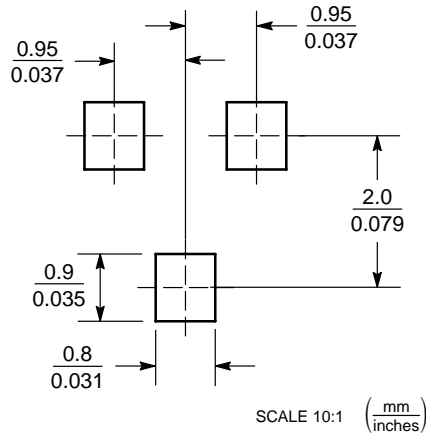
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.
3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH THICKNESS. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL.
4. 318-01, -02, AND -06 OBSOLETE, NEW STANDARD 318-09.

DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.1102	0.1197	2.80	3.04
B	0.0472	0.0551	1.20	1.40
C	0.0385	0.0498	0.99	1.26
D	0.0140	0.0200	0.36	0.50
G	0.0670	0.0826	1.70	2.10
H	0.0040	0.0098	0.10	0.25
J	0.0034	0.0070	0.085	0.177
K	0.0180	0.0236	0.45	0.60
L	0.0350	0.0401	0.89	1.02
S	0.0830	0.0984	2.10	2.50
V	0.0177	0.0236	0.45	0.60

STYLE 12:


- PIN 1. CATHODE
- CATHODE
- ANODE

SOLDERING FOOTPRINT*



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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